TOSHIBA **TLP3502**

TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-TRIAC

TLP3502

PROGRAMMABLE CONTROLLERS

AC-OUTPUT MODULE

TRICA DRIVER

SOLID STATE RELAY

The TOSHIBA TLP3502 consists of a photo-triac optically coupled to a gallium arsenide infrared emitting diode in a 8 lead plastic DIP package.

Peak Off-State Voltage : 400V (MIN.)

Trigger LED Current : 10mA (MAX.)

On-State Current : $0.5A_{rms}(MAX.)$

Isolation Voltage $: 2500 V_{rms} (MIN.)$

: UL 1577, File No. E67349 UL Recognized

Trigger LED Current

CLASSI- FICATION*	TRIGGER LED	MADWING OF		
	$V_{\mathrm{T}}=6V$,	MARKING OF CLASSIFICATION		
	MIN.	MAX.		
(IFT5)	_	5.0	T5	
(IFT7)	_	7.0	T5, T7	
Standard	_	10	T5, T7, Blank	

*Ex. (IFT5) : TLP3502 (IFT5)

(Note) Application type name for certification test, please use standard product type name, i.e.

TLP3502 (IFT5): TLP3502

 9.66 ± 0.25 7.85~8.80

Unit in mm

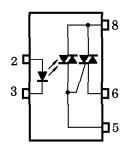
11-10C3

Weight: 0.52g

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PIN CONFIGURATION (TOP VIEW)

11-10C3



2: ANODE

3: CATHODE

5: TRIAC GATE

6: TRIAC T1

8: TRIAC T2

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 Gallium arsenide (GaAs) is a substance used in the products described in this document. GaAs dust and fumes are toxic. Do not break, cut or pulverize the product, or use chemicals to dissolve them. When disposing of the products, follow the appropriate regulations. Do not dispose of the products with other industrial waste or with domestic garbage.

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MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC			SYMBOL	RATING	UNIT	
	Forward Current	$I_{\mathbf{F}}$	50	mA		
LED	Forward Current Derating (Ta	⊿I _F /°C	-0.7	mA/°C		
	Peak Forward Current (100 µs puls	I_{FP}	1	A		
	Reverse Voltage		$v_{ m R}$	5	V	
	Junction Temperature	Тј	125	$^{\circ}\mathrm{C}$		
	Off-State Output Terminal Voltage	$V_{ m DRM}$	400	V		
	On-State RMS Current	Ta=40°C	Im (Daso)	0.5	A	
OR		Ta=60°C	IT (RMS)	0.35		
$_{\rm CI}$	On-State Current Derating (Ta≥40	$\Delta I_{\mathrm{T}}/^{\circ}\mathrm{C}$	-7.2	mA/°C		
DETE	Peak Current from Snubber Circuit pulse, 120pps)	I_{SP}	2	A		
	Peak Nonrepetitive Surge Current	I_{TSM}	5	A		
	Junction Temperature	$\mathrm{T_{j}}$	110	°C		
Sto	Storage Temperature Range			-40~125	°C	
Operating Temperature Range			$egin{array}{c} T_{ m stg} \ T_{ m opr} \end{array}$	-20~80	$^{\circ}\mathrm{C}$	
Lea	Lead Soldering Temperature (10s)			260	°C	
Isol	Isolation Voltage (AC, 1 min., R.H.≤60%) (Note)			2500	Vrms	

(Note) Device considered a two terminal: LED side pins shorted together and DETECTOR side pins shorted together.

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	v_{AC}	_	_	120	Vac
Forward Current	${f I_F}$	15	20	25	mA
Peak Current from Snubber Circuit	I_{SP}	_	_	1	A
Operating Temperature	$T_{ m opr}$	-25	_	85	°C

INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

	CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
	Forward Voltage	$ m V_{f F}$	$I_{\mathbf{F}} = 10 \text{mA}$	1.0	1.15	1.3	V
LE]	Reverse Current	$I_{\mathbf{R}}$	$V_R = 5V$	_	_	10	μ A
	Capacitance	C_{T}	V=0, f=1MHz		30	_	pF
	Peak Off-State Current	$I_{ m DRM}$	V _{DRM} =400V, Ta=110°C	_		100	μ A
OR	Peak On-State Voltage	$ m V_{TM}$	$I_{TM} = 0.75A$	-	_	3.0	V
CT	Holding Current	${ m I_{H}}$	_	_		25	mA
ETE	Critical Rate of Rise of Off-State Voltage	dv / dt	$V_{in} = 120 Vrms$ (Fig.1)	200	500	_	V/μs
Q	Critical Rate of Rise of Commutating Voltage	dv / dt (c)	$V_{ m in}\!=\!120 { m Vrms},~ I_{ m T}\!=\!0.5 { m Arms}$ (Fig.1)	_	5	_	V / μs

COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Trigger LED Current	I_{FT}	$V_T = 6V$	_	_	10	mA
Capacitance (Input to Output)	c_{S}	V _S =0, f=1MHz	_	1.5	_	pF
Isolation Resistance	$R_{\mathbf{S}}$	$V_S = 500V$	5×10^{10}	10^{14}	_	Ω
	$_{ m BV_S}$	AC, 1 minute	2500	1	_	Vrms
Isolation Voltage		AC, 1 second, in oil	_	5000		
		DC, 1 minute, in oil	_	5000	_	v_{dc}

Fig.1 : dv/dt TEST CIRCUIT

